

DN2302S N-Channel MOSFET

General description

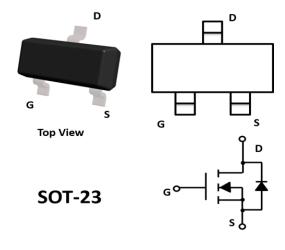
N-Channel MOSFET

FEATURES

- V_{DS}=20V
- I_D=3.2A
- R_{DS(ON)}(at V_{GS}=4.5V)<60 m Ω
- R_{DS(ON)}(at V_{GS}=2.5V)<80 m Ω
- Trench Power MOSFET technology
- High Power and current handing capability
- High density cell design for low R_{DS(ON)}

APPLICATIONS

- DC-DC Converters
- LED Driver
- Switching Circuits



Device Marking Code:

Device Type	Device Marking
DN2302S	A2sHB

Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Drain-Source Voltage	$V_{ m DS}$	20	V
Gate-Source Voltage	Vgs	±10	V
Continuous Drain Current	I_D	3.2	A
Pulsed Drain Current (note 1)	Ідм	12.8	A
Maximum Power Dissipation	P_D	1.0	W
Thermal Resistance from Junction to Ambient (note 2)	R _θ JA	125	°C/W
Junction and Storage Temperature	Tj. Tstg	-50~+150	℃

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Electrical Characteristics

Parameters	Symbol	Test Condition	Min	Тур	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 250 \mu A$	20	1	-	V
Zero gate voltage drain current	Idss	$V_{DS} = 20V, V_{GS} = 0V$			1	μΑ
Gate-body leakage current	Igss	$V_{GS} = \pm 10V, V_{DS} = 0V$			±100	nA
Gate threshold voltage (note 3)	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.4	0.6	1.0	V
	RDS(on)	$V_{GS} = 4.5V, I_D = 3A$		48	60	mΩ
Drain-source on-resistance (note 3)		$V_{GS} = 3.3V, I_D = 2A$		55	70	mΩ
		$V_{GS} = 2.5V$, $I_D = 1A$		66	80	mΩ
Diode forward voltage (note 3)	V_{SD}	$I_{S}=1A,V_{GS}=0V$		0.82	1.2	V

Dynamic Characteristics (note4)				
Input Capacitance	Ciss	101111 011 6	 160	 pF
Output Capacitance	Coss	V_{DS} = 10V, V_{GS} =0V, f =1MHz	 30	 pF
Reverse Transfer Capacitance	Crss	1	 25	 pF
Switching Characteristics (note 4)				
Turn-on delay time	td(on)	V_{DD} = 10V, I_{D} = 2A, R_{G} = 3.3 Ω , V_{GS} = 4.5V	 8	 ns
Turn-on rise time	tr		 30	 ns
Turn-off delay time	td(off)		 19	 ns
Turn-off fall time	tf		 28	 ns
Total Gate Charge	Qg	V _{DS} = 10V,I _D =3A, V _{GS} =5V	 4.0	 nC
Gate-Source Charge	Qgs		 0.4	 nC
Gate-Drain Charge	Qgd		 1.2	 nC

Note:

1) Repetitive rating: Pluse width limited by maximum junction temperature

2)Surface Mounted on FR4 board, $t \le 10$ sec.

3)Pulse test : Pulse width \leq 300 μ s, duty cycle \leq 2%.

4) Guaranteed by design, not subject to production.

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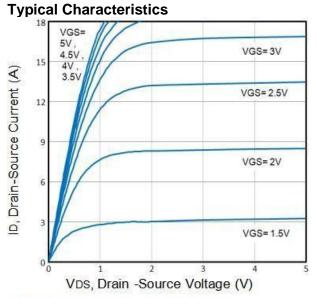


Fig1. Typical Output Characteristics

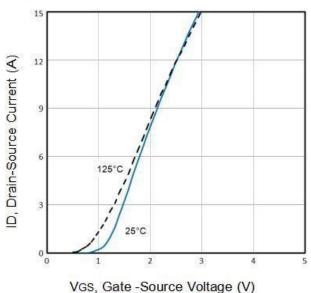


Fig3. Typical Transfer Characteristics

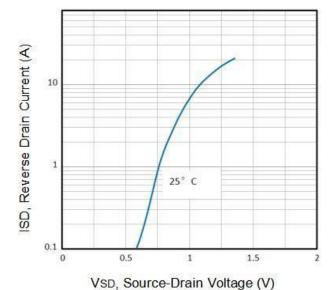


Fig5. Typical Source-Drain Diode Forward Voltage www.doeshare.net

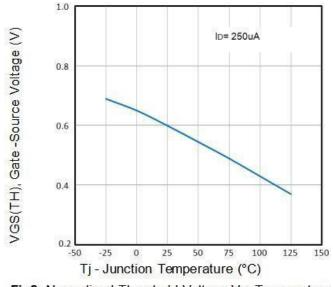


Fig2. Normalized Threshold Voltage Vs. Temperature

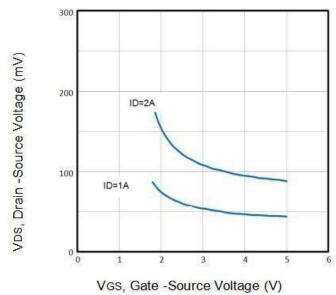
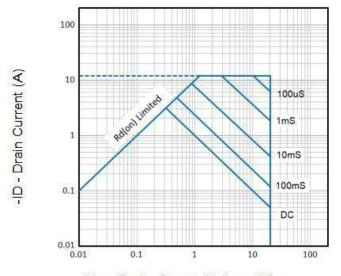


Fig4. Drain -Source Voltage vs Gate -Source Voltage



VDS, Drain -Source Voltage (V)

Fig6. Maximum Safe Operating Area

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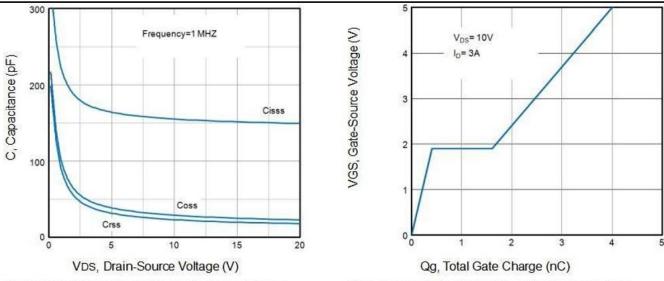
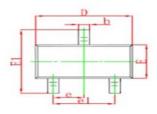
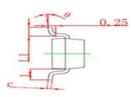


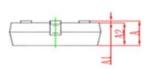
Fig7. Typical Capacitance Vs. Drain-Source Voltage

Fig8. Typical Gate Charge Vs. Gate-Source Voltage

SOT-23 Package information

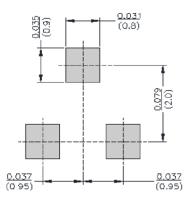






Cumbal	Dimentions	in Millimeter	Dimentions in Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035 0.04		
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.800	3.000	0.110	0.118	
E	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.95	0.950Type		7Туре	
e1	1.800	2.000	0.071	0.079	
L	0.550REF		0.220REF		
L1	0.300	0.500	0.012	0.020	
θ	0 °	8 °	0 °	8 °	

SOT-23 Suggested Pad Layout



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